# BC817-16LT1, BC817-25LT1, BC817-40LT1

# **General Purpose Transistors**

# **NPN Silicon**

### **Features**

• Pb-Free Packages are Available

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	45	V
Collector - Base Voltage	V <sub>CBO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current – Continuous	I <sub>C</sub>	500	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

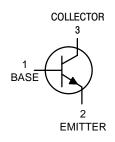
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.



# ON Semiconductor®

http://onsemi.com





SOT-23 CASE 318 STYLE 6

# MARKING DIAGRAM



xx = Specific Device Code
D = Date Code

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# BC817-16LT1, BC817-25LT1, BC817-40LT1

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 mA)	V <sub>(BR)</sub> CEO	45	-	-	V	
Collector – Emitter Breakdown Voltage (V <sub>EB</sub> = 0, I <sub>C</sub> = –10 μA)	V <sub>(BR)</sub> CES	50	-	-	V	
Emitter – Base Breakdown Voltage ( $I_E = -1.0 \mu A$ )	V <sub>(BR)EBO</sub>	5.0	-	_	V	
Collector Cutoff Current $(V_{CB} = 20 \text{ V})$ $(V_{CB} = 20 \text{ V}, T_A = 150^{\circ}\text{C})$	I <sub>CBO</sub>	- -	- -	100 5.0	nA μA	
ON CHARACTERISTICS						
DC Current Gain	h <sub>FE</sub>	100 160 250 40	- - - -	250 400 600 –	-	
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA)	V <sub>CE(sat)</sub>	-	-	0.7	V	
Base – Emitter On Voltage (I <sub>C</sub> = 500 mA, V <sub>CE</sub> = 1.0 V)	V <sub>BE(on)</sub>	-	-	1.2	V	
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz)	f <sub>T</sub>	100	-	-	MHz	
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	C <sub>obo</sub>	-	10	_	pF	

# ORDERING INFORMATION

Device	Specific Marking Code	Package	Shipping <sup>†</sup>
BC817-16LT1	6A	SOT-23	
BC817-16LT1G	6A	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC817-16LT3	6A	SOT-23	10,000 / Tape & Reel
BC817-25LT1	6B	SOT-23	
BC817-25LT1G	6B	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC817-25LT3	6B	SOT-23	
BC817-25LT3G	6B	SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC817-40LT1	6C	SOT-23	
BC817-40LT1G	6C	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC817-40LT3	6C	SOT-23	
BC817-40LT3G	6C	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SBC817-40LT1	6C	SOT-23	3,000 / Tape & Reel
SBC817-40LT3	6C	SOT-23	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BC817-16LT1, BC817-25LT1, BC817-40LT1

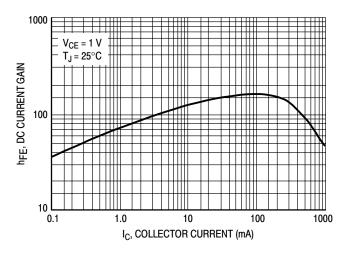


Figure 1. DC Current Gain

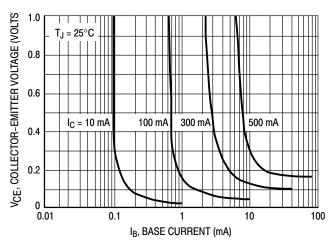


Figure 2. Saturation Region

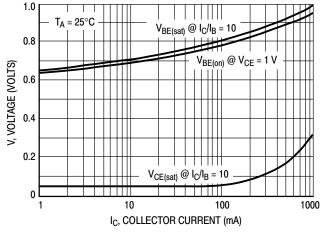
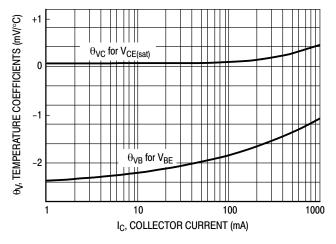


Figure 3. "On" Voltages



**Figure 4. Temperature Coefficients** 

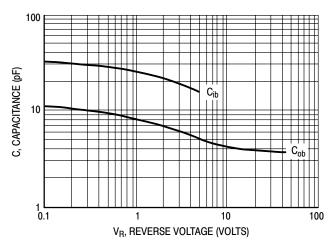
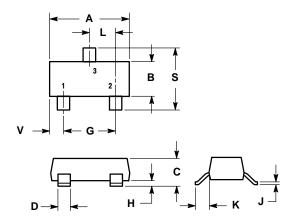


Figure 5. Capacitances

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# PACKAGE DIMENSIONS

# SOT-23 (TO-236) CASE 318-09 **ISSUE AI**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  MAXIUMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- 318-01, -02, AND -06 OBSOLETE, NEW STANDARD 318-09.

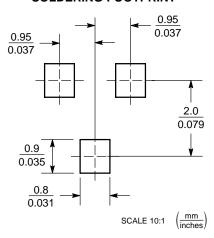
	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0385	0.0498	0.99	1.26	
D	0.0140	0.0200	0.36	0.50	
G	0.0670	0.0826	1.70	2.10	
Н	0.0040	0.0098	0.10	0.25	
J	0.0034	0.0070	0.085	0.177	
K	0.0180	0.0236	0.45	0.60	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.0984	2.10	2.50	
V	0.0177	0.0236	0.45	0.60	

### STYLE 6:

BASE

- **EMITTER**
- COLLECTOR

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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